

Dual Smart Card Interface with Serial Control

FEATURES

- Compatible with ISO7816-3 and EMV Electrical Specifications
- Power Management and Control for Two Smart Cards
- Control/Status Serial Port May be Daisy-Chained for Multicard Applications
- Automatic Shutdown on Electrical Faults
- Buck/Boost Charge Pump Generates 5V, 3V or 1.8V Outputs (Smart Card Classes A, B and C)*
- Independent 5V/3V/1.8V Level Control for Both Cards
- Automatic Level Translation
- Supervisory Functions Prevent Smart Card Faults
- Low Operating Current: 250 μ A Typical
- Ultralow Shutdown Current
- >10kV ESD on Smart Card Pins
- Small 32-Pin 5mm $\times$ 5mm QFN Package

APPLICATIONS

- Handheld Payment Terminals
- Pay Telephones
- ATM Machines
- POS Terminals
- Computer Keyboards
- Multiple S.A.M. Sockets

DESCRIPTION

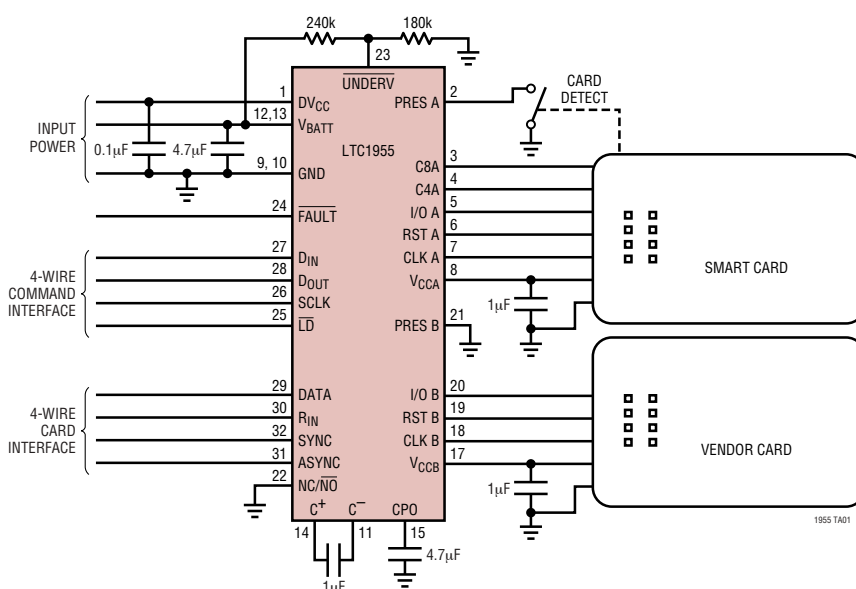
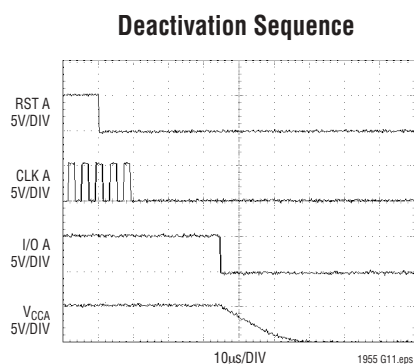
The LTC[®]1955 provides all necessary supervisory and power control functions for two smart cards, two S.A.M. cards or a combination of S.A.M. and smart cards. It provides a charge pump for battery powered applications as well as all necessary level shifting circuitry.

The card voltages can be independently set to 1.8V, 3V or 5V. Both card interfaces include a card detection channel with automatic debounce circuitry. To reduce wiring costs, the LTC1955 interfaces to a microcontroller via a simple 4-wire serial interface. Multiple devices may be connected in daisy-chain fashion so that the number of wires to the card socket board is independent of the number of sockets. Status data is returned over the same interface.

Extensive security features ensure proper deactivation sequencing in the event of a supply fault or a smart card electrical fault. The smart card pins can withstand greater than 10kV ESD in-situ with no additional components. The LTC1955 is available in a low profile (0.75mm) 5mm $\times$ 5mm QFN package.

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 *Protected by U.S. Patents including 6356140, 6411531.

TYPICAL APPLICATION



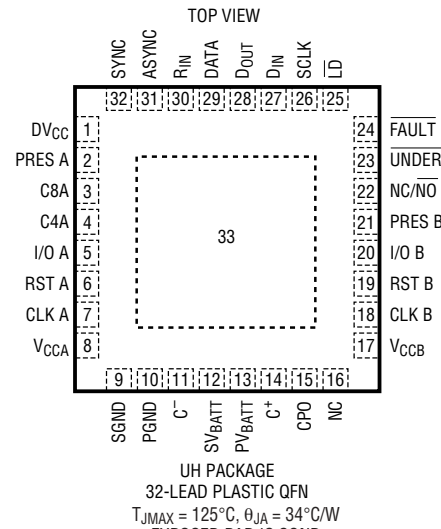
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ABSOLUTE MAXIMUM RATINGS (Note 1)

V_{BATT} , DV_{CC} , CPO, $\overline{FAULT}$,
 $\overline{UNDERV}$ to GND -0.3V to 6.0V
 PRES A/PRES B, DATA, R_{IN} , SYNC, ASYNC,
 LD, D_{IN} , SCLK to GND -0.3V to (DV_{CC} + 0.3V)
 I/O A -0.3V to (V_{CCA} + 0.3V)
 I/O B -0.3V to (V_{CCB} + 0.3V)

I_{VCCA}/I_{VCCB} 80mA
 V_{CCA}/V_{CCB} Short-Circuit Duration Indefinite
 Operating Ambient Temperature Range
 (Note 4) -40°C to 85°C
 Storage Temperature Range -65°C to 125°C

PACKAGE/ORDER INFORMATION

	ORDER PART NUMBER LTC1955EUH UH PART MARKING 1955
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Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_{PVBATT} = V_{SVBATT} = 3.3\text{V}$, $DV_{CC} = 3.3\text{V}$ unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Input Power Supply					
V_{BATT} Operating Voltage	●	2.7		5.5	V
$I_{PVBATT} + I_{SVBATT}$ Operating Current	$V_{CCA} = 5\text{V}$, $V_{CCB} = 0\text{V}$, $I_{CCA} = 0\mu\text{A}$ ● $V_{CCA} = V_{CCB} = 5\text{V}$, $I_{CCA} = I_{CCB} = 0\mu\text{A}$ ●		250 350	400 500	μA μA
$I_{PVBATT} + I_{SVBATT}$ Shutdown Current	No Cards Present, $V_{CPO} = 0\text{V}$ ●		0.75	1.75	μA
DV_{CC} Operating Voltage	●	1.7		5.5	V
I_{DVCC} Operating Current	●		10	25	μA
I_{DVCC} Shutdown Current	●		0.5	1.5	μA
Charge Pump					
R_{OLCP} 5V Mode Open-Loop Output Resistance	$V_{BATT} = 3.075\text{V}$, $I_{CPO} = I_{CCA} + I_{CCB} = 120\text{mA}$ (Note 3) ●		5.7	8.5	Ω
CPO Turn On Time	$I_{CCA/B} = 0\text{mA}$, 10% to 90% ●		0.6	1.5	ms

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ELECTRICAL CHARACTERISTICS

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SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Smart Card Supplies V _{CCA} , V _{CCB}						
V _{CCA/B} Output Voltage	5V Mode, 0 < I _{CCA/B} < 60mA	●	4.65	5.0	5.35	V
	3V Mode, 0 < I _{CCA/B} < 50mA	●	2.75	3.0	3.25	V
	1.8V Mode, 0 < I _{CCA/B} < 30mA	●	1.65	1.8	1.95	V
V _{CCA/B} Turn On-Time	I _{CCA/B} = 0mA, 10% to 90%	●		0.8	1.5	ms
Undervoltage Detection	Relative to Nominal Output	●	−9	−5	−2.5	%
Overcurrent Detection	5V Mode	●	65	100	135	mA
Smart Card Detection						
Debounce Time (↘ PRES A/B to ↗ D15/D7)	V _{NC/NO} = 0V	●	20	35	60	ms
PRES A, PRES B Pull-Up Current	V _{PRESA/B} = 0	●		1.25	2.5	μA
Deactivation Time (↘ RST to V _{CC} = 0.4V)	I _{CCA/B} = 0mA, C _{VCCA/B} = 1μF	●		20	250	μs
CLK A, CLK B						
Low Level Output Voltage (V _{OL}), (Note 2)	Sink Current = −200μA	●			0.2	V
High Level Output Voltage (V _{OH}), (Note 2)	Source Current = 200μA	●	V _{CCA/B} − 0.2			V
Rise/Fall Time (Note 2)	Loaded with 50pF, 10% to 90%	●			16	ns
CLK A, CLK B Frequency (Note 2)		●	10			MHz
RST A, RST B, C4A, C8A						
Low Level Output Voltage (V _{OL}), (Note 2)	Sink Current = −200μA	●			0.2	V
High Level Output Voltage (V _{OH}), (Note 2)	Source Current = 200μA	●	V _{CCA/B} − 0.2			V
Rise/Fall Time (Note 2)	Loaded with 50pF, 10% to 90%	●			100	ns
I/O A, I/O B						
Low Level Output Voltage (V _{OL}), (Note 2)	Sink Current = −1mA (V _{DATA} = 0V)	●			0.3	V
High Level Output Voltage (V _{OH}), (Note 2)	Source Current = 20μA (V _{DATA} = V _{DVCC})	●	0.85 • V _{CCA/B}			V
Rise/Fall Time (Note 2)	Loaded with 50pF, 10% to 90%	●			500	ns
Short Circuit Current (Note 2)	V _{DATA} = 0V	●		5	10	mA
DATA						
Low Level Output Voltage (V _{OL})	Sink Current = −500μA (V _{I/OA/B} = 0V)	●			0.3	V
High Level Output Voltage (V _{OH})	Source Current = 20μA (V _{I/OA/B} = V _{CCA/B})	●	0.8 • DV _{CC}			V
Rise/Fall Time	Loaded with 50pF, 10% to 90%	●			500	ns
R _{IN} , D _{IN} , SCLK, LD, SYNC, ASYNC, NC/NO						
Low Input Threshold (V _{IL})		●			0.15 • DV _{CC}	V
High Input Threshold (V _{IH})		●	0.85 • DV _{CC}			V
Input Current (I _{IH} /I _{IL})		●	−1		1	μA
D _{OUT}						
Low Level Output Voltage (V _{OL})	Sink Current = −200μA	●			0.3	V
High Level Output Voltage (V _{OH})	Source Current = 200μA	●	DV _{CC} − 0.3			V
UNDERV						
Threshold		●	1.17	1.23	1.29	V
Leakage Current	V _{UNDERV} = 3.3V	●			50	nA

ELECTRICAL CHARACTERISTICS

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PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
FAULT					
Low Level Output Voltage (V_{OL})	Sink Current = $-200\mu\text{A}$	●	0.005	0.3	V
Leakage Current	$V_{FAULT} = 5.5\text{V}$	●		1	μA

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Serial Port Timing						
t_{DS}	D_{IN} Valid to SCLK Setup	●	8			ns
t_{DH}	D_{IN} Valid to SCLK Hold	●	8			ns
t_{DD}	D_{OUT} Output Delay	$C_{LOAD} = 15\text{pF}$	●	15	60	ns
t_L	SCLK Low Time	●	50			ns
t_H	SCLK High Time	●	50			ns
t_{LW}	$\overline{LD}$ Pulse Width	●	50			ns
t_{CL}	SCLK to $\overline{LD}$	●	50			ns
t_{LC}	$\overline{LD}$ to SCLK	●	0			ns

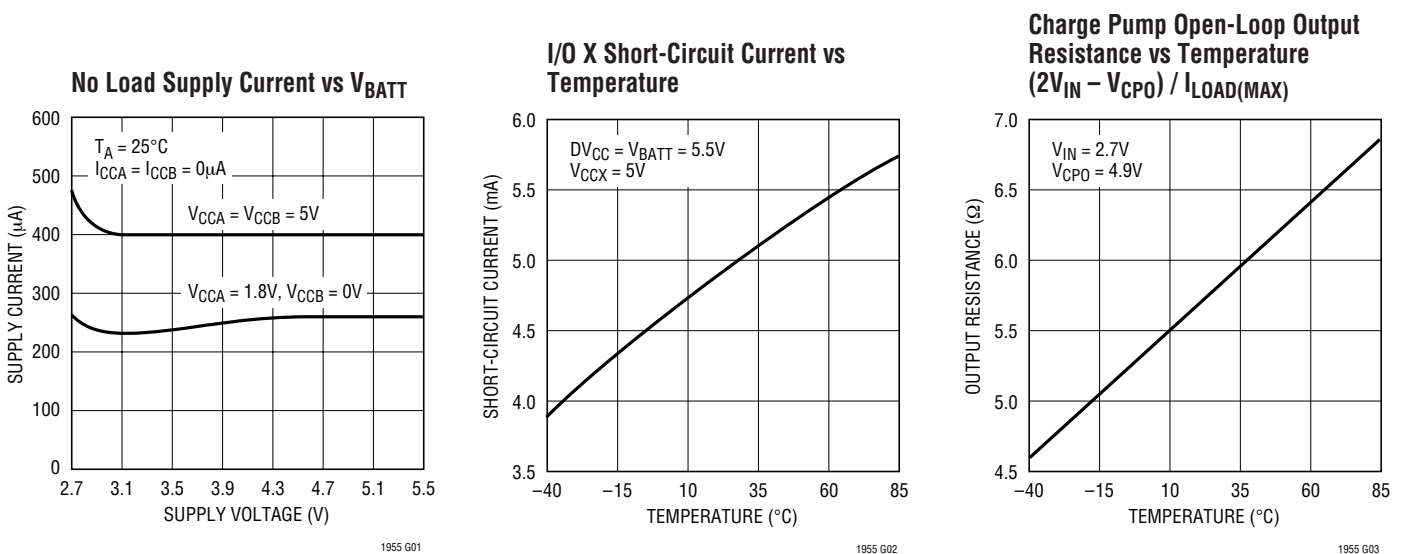
Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: This specification applies to all three smart card voltage classes: 1.8V, 3V and 5V.

Note 3: $R_{OLCP} = (2V_{BATT} - V_{CPO}) / I_{CPO}$; V_{CPO} will depend upon total load ($I_{CCA} + I_{CCB}$) and minimum supply voltage V_{BATT} . See Figure 6.

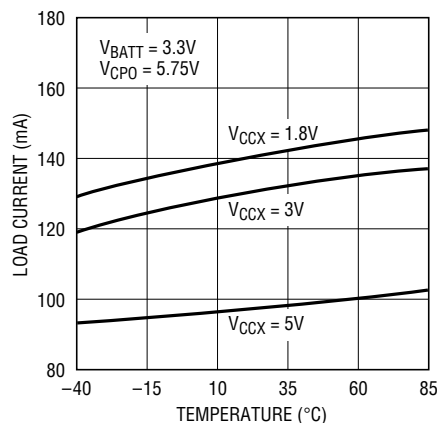
Note 4: The LTC1955E is guaranteed to meet performance specifications from 0°C to 70°C . Specifications over the -40°C to 85°C operating ambient temperature range are assured by design, characterization and correlation with statistical process controls.

TYPICAL PERFORMANCE CHARACTERISTICS

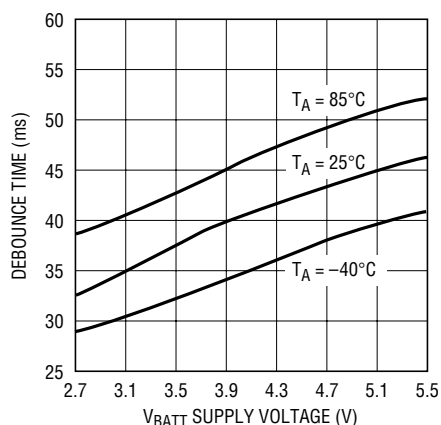


TYPICAL PERFORMANCE CHARACTERISTICS

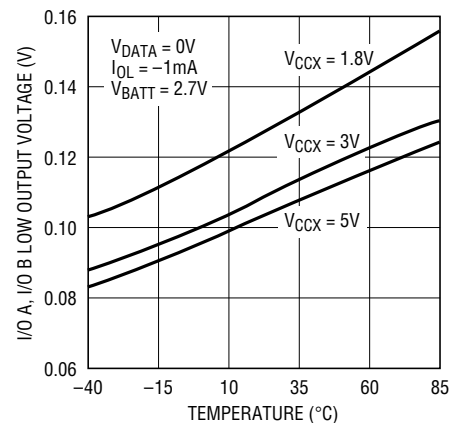
V_{CCX} Overcurrent Shutdown Threshold vs Temperature



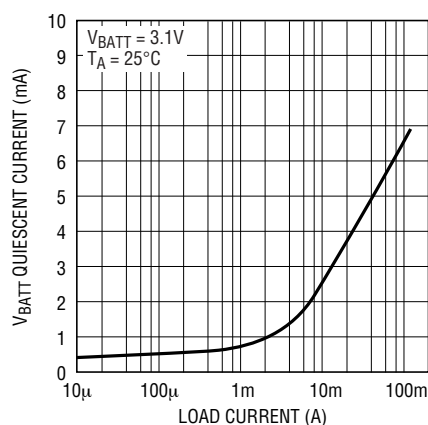
Card Detection Debounce Time vs V_{BATT} Supply Voltage



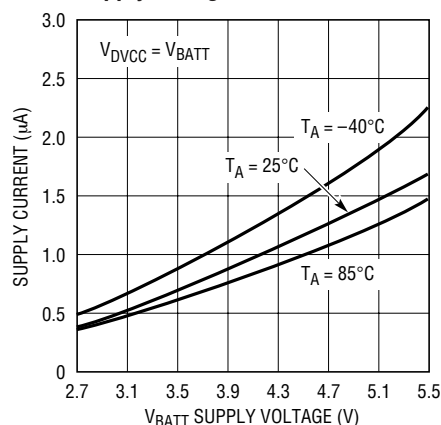
Bidirectional Channel (I/O A, I/O B) Low Output Level vs Temperature



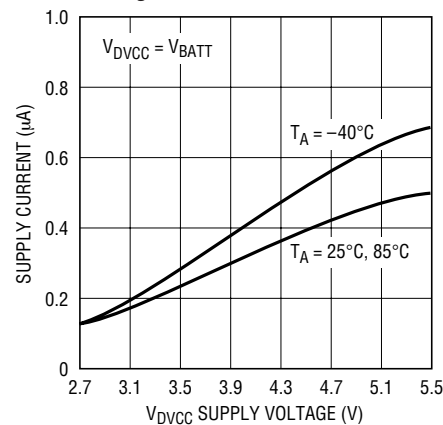
V_{BATT} Quiescent Current [I_{BATT} - 2(I_{CCA} + I_{CCB})] vs Load Current



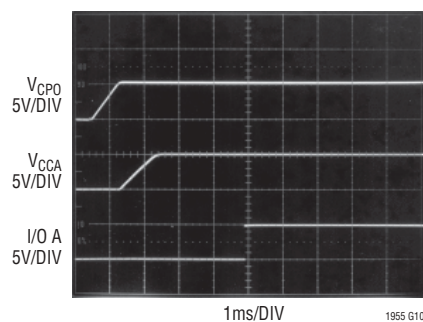
V_{BATT} Shutdown Current vs Supply Voltage



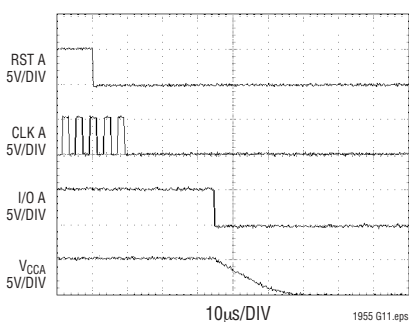
DV_{CC} Shutdown Current vs Supply Voltage



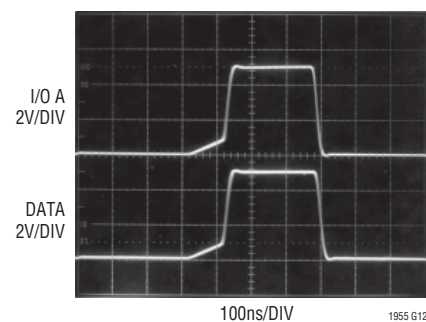
Charge Pump and LDO Activation



Deactivation Sequence



Data - I/O Channel, C_L = 50pF



PIN FUNCTIONS

SV_{BATT}: Power. Supply voltage for analog sections of the LTC1955.

PV_{BATT}: Power. Supply voltage for the charge pump.

DV_{CC}: Power. Reference voltage for the control logic.

SGND: Ground. Signal ground for analog sections of the LTC1955. The exposed pad must be soldered to PCB ground.

PGND: Ground. Power ground for the charge pump. This pin should be connected directly to a low impedance ground plane.

CPO: Charge Pump. CPO is the output of the charge pump. When one or both of the smart cards requires power, the charge pump will charge CPO to either 3.7V or 5.35V depending on what smart card voltages are required. A low impedance 4.7μF X5R or X7R ceramic capacitor is required on CPO.

C⁺, C⁻: Charge Pump. Charge pump flying capacitor pins. A 1μF X5R or X7R ceramic capacitor should be connected from C⁺ to C⁻.

DATA: Input/Output. Microcontroller side data I/O pin. The DATA pin provides the bidirectional communication path to both smart cards. One, both or neither of the cards may be selected to communicate via the DATA pin. If several LTC1955s are connected in parallel, the DATA pin can be made high impedance by selecting neither card. The C4A and C8A synchronous card pins can be selected to connect to the DATA pin via the serial port (see Table 4).

R_{IN}: Input. The R_{IN} pin supplies the RST signal to both smart cards. It is level shifted and transmitted directly to the RST pin of a selected card socket. When a card is deselected, the RST A/RST B pin for that channel is latched at its current state.

SYNC: Input. The SYNC pin provides the clock input for synchronous smart cards. When a synchronous card is selected, its CLK pin follows SYNC directly. When a

synchronous card is deselected, the CLK A/CLK B pin for that channel is latched at its current state.

ASYN: Input. The ASYN pin provides the clock input for asynchronous cards and should be connected to a free running clock. The clock signal to the smart card can be a ÷1, ÷2, ÷4 or ÷8 version of the signal on ASYN. Asynchronous cards can also be placed in clock stop mode with the clock stopped either high or low.

D_{IN}: Input. Input for the serial port. Command data is shifted into D_{IN} synchronously with SCLK. D_{IN} can be connected directly to a microcontroller or the D_{OUT} pin of another LTC1955 for daisy chained operation.

D_{OUT}: Output. Output for the serial port. Smart card status data is shifted out of D_{OUT} synchronously with SCLK. D_{OUT} can be connected directly to a microcontroller or the D_{IN} pin of another LTC1955 for daisy chained operation.

SCLK: Input. The SCLK pin clocks the serial port. Each new data bit is received on the rising edge of SCLK. SCLK should be left high during idle times and should not be clocked when $\overline{\text{LD}}$ is low.

$\overline{\text{LD}}$: Input. The falling edge of this pin loads the current state of the shift register into the command register. Command changes to both smart card channels will be updated on the falling edge of $\overline{\text{LD}}$. The rising edge of $\overline{\text{LD}}$ latches status information from the smart card channels into the shift register for the next read/write cycle.

NC/ $\overline{\text{NO}}$: Input. This pin controls the activation level of the PRES A/PRES B pins. When it is high (DV_{CC}), the PRES pins are active high. When it is low (GND), the PRES pins are active low. When a ground side N.O. switch is used, the NC/ $\overline{\text{NO}}$ pin should be grounded. When a ground side N.C. switch is used, the NC/ $\overline{\text{NO}}$ pin should be connected to DV_{CC}.

Note: If an N.C. switch is used, a small current (several microamperes) will flow through the switch whenever a smart card is not present. For ultralow power consumption in shutdown, an N.O. switch is optimum.

PIN FUNCTIONS

PRES A/PRES B: Card Socket. The PRES A/PRES B pins are used to detect the presence of the smart cards. They can be connected to either normally open or normally closed detection switches on the smart card acceptor's sockets. The NC/ $\overline{\text{NO}}$ pin should be set appropriately. These pins have a pull-up current source on-chip so no external components are required.

C4A/C8A: Card Socket. These pins connect to the C4 and C8 pins of synchronous memory cards on smart card socket A. The signal for these pins is unidirectional and can only be sent to the card. Data for C4A and C8A is transmitted via the DATA pin and may be selected in place of I/OA via the serial port (see Table 4). When either C4A or C8A is selected, it will follow the DATA pin. When it is deselected, it will remain latched at its current state.

I/O A/I/O B: Card Socket. The I/O A/I/O B pins connect to the I/O pins of the respective smart card sockets. When a smart card is selected, its I/O pin connects to the DATA pin. When a smart card is deselected, its I/O A/I/O B pin returns to the idle state (H).

RST A/RST B: Card Socket. These pins should be connected to the RST pins of the respective smart card sockets. The RST A/RST B signals are derived from the R_{IN} pin. When a card is selected, its RST pin follows R_{IN} . When a card is deselected, the RST A/RST B pin for that channel holds the current value on R_{IN} .

CLK A/CLK B: Card Socket. The CLK A/CLK B pins should be connected to the CLK pins of the respective smart card sockets. The CLK A/CLK B signals can be derived from either the SYNC input or the ASYNC input depending on which type of card is being accessed. The card type is selected via the serial port (see Tables 1 and 3).

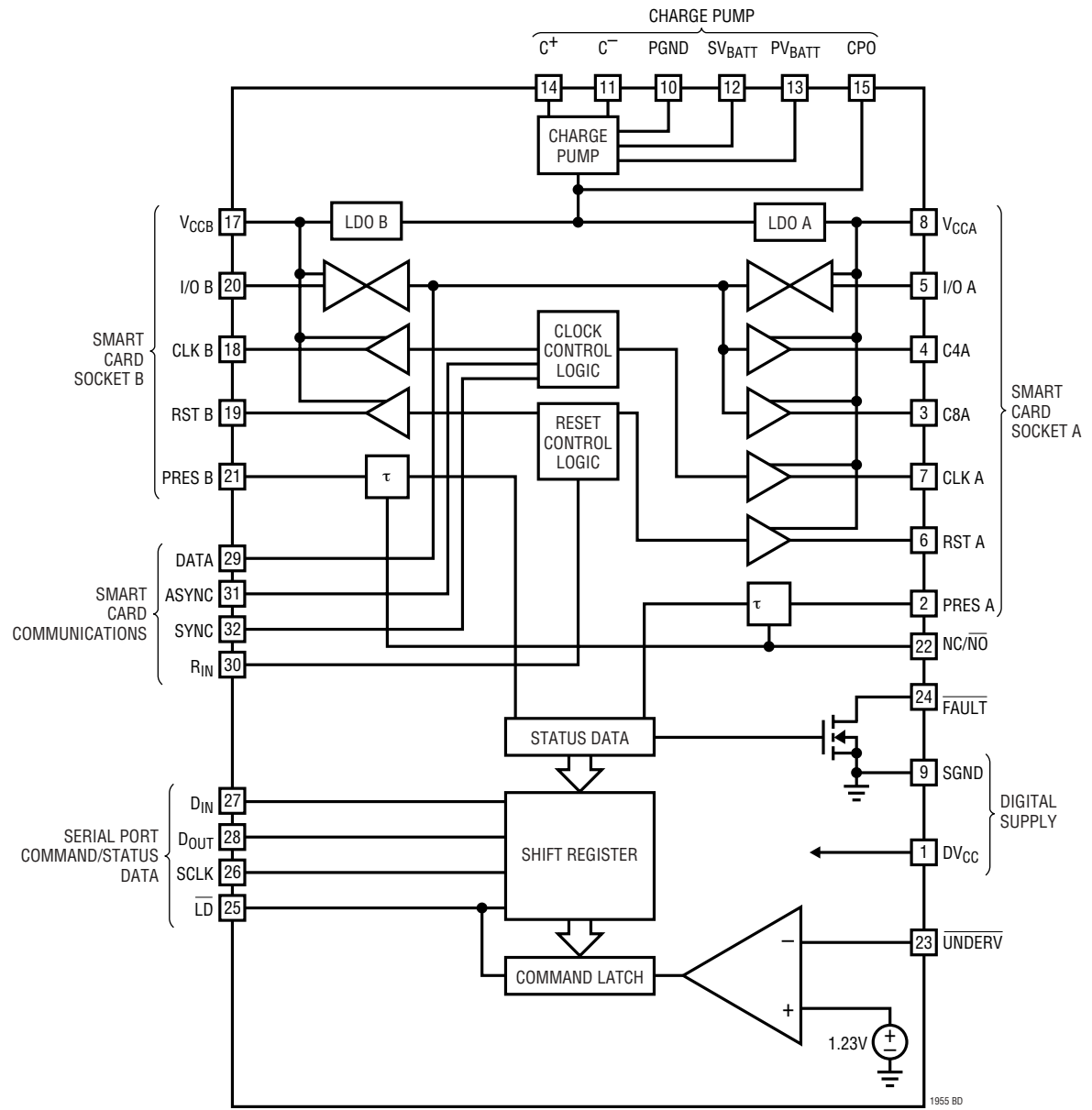
V_{CCA} , V_{CCB} : Card Socket. The V_{CCA} / V_{CCB} pins should be connected to the V_{CC} pins of the respective smart card sockets. The activation of a V_{CCA} / V_{CCB} pin is controlled by the serial port (see Tables 1 and 2) and can be set to 0V, 1.8V, 3V or 5V. The voltage levels of the two card sockets are controlled independently for maximum flexibility.

$\overline{\text{FAULT}}$: Output. The $\overline{\text{FAULT}}$ pin can be used as an interrupt to a microcontroller to indicate when a fault has occurred. It is an open drain output, which is logically equivalent to $\text{D4} + \text{D5} + \text{D12} + \text{D13}$. (See Table 1)

$\overline{\text{UNDERV}}$: Input. The $\overline{\text{UNDERV}}$ pin provides security by supplying a precision undervoltage threshold for external supply monitoring. An external resistive voltage divider programs the desired undervoltage threshold. Once $\overline{\text{UNDERV}}$ falls below 1.23V, the LTC1955 automatically begins the deactivation sequence on any channel that is active.

If external supply monitoring is not required, the $\overline{\text{UNDERV}}$ pin should be connected to either SV_{BATT} or DV_{CC} .

BLOCK DIAGRAM



OPERATION

Serial Port

The microcontroller compatible serial port provides all of the command and control inputs for the LTC1955 as well as the status of the two smart cards. Data on the D_{IN} input is loaded on the rising edge of SCLK. D15 is loaded first and D0 last. At the same time the command bits are being shifted into the D_{IN} input, the status bits are being shifted out of the D_{OUT} output. The status bits are presented to D_{OUT} on the rising edge of SCLK. Once all bits have been clocked into the shift register, the command data is loaded into the command latch by bringing $\overline{LD}$ low. At this time the command latch is updated and the LTC1955 will begin to act on the new command set. When $\overline{LD}$ is low, the shift register is transparent to the status data of the two smart card channels. The status data is latched into the shift register on the rising edge of $\overline{LD}$. SCLK should be held in the high state when idle and should only be clocked when $\overline{LD}$ is high. Likewise $\overline{LD}$ should only be brought high when SCLK is high. Figure 2 shows the operation of the serial port.

Multiple LTC1955s may be daisy-chained together by connecting the D_{OUT} pin of one LTC1955 to the D_{IN} pin of another. Figure 7 shows an example of multiple LTC1955s daisy chained together.

The maximum clock rate for the serial port is 10MHz.

The serial port controls the following parameters of each smart card socket:

- Selection/deselection of a smart card
- V_{CC} voltage level of each card (5V/3V/1.8V/0V)
- Clock mode of each card (synchronous or asynchronous)

- Operating mode of asynchronous cards (clock stop high, low, $\div 1$, $\div 2$, $\div 4$ or $\div 8$)
- Selection of the I/O, C4 or C8 pins for card socket A

The serial port provides the following status data:

- It indicates the presence or absence of the smart cards.
- It indicates the readiness of the smart card V_{CC} supplies. Communication with a smart card is disabled until its power supply voltage has reached the final value.
- It indicates fault status. In the event of an electrical or ATR fault, the fault is reported. For electrical faults, the LTC1955 will automatically deactivate the smart card.

Table 1 illustrates the command inputs and status outputs associated with each bit of the serial data word.

Three voltage options are available from the LTC1955: 5V, 3V and 1.8V. Bits D0, D1 (card B) and D8, D9 (card A) determine which voltage is selected. Setting both control bits of a channel to 0 deactivates that channel and sets the smart card supply voltage to 0V. If both channels are deactivated, the LTC1955 is in shutdown. Table 2 shows the operation of the supply control bits.

The CLK A/CLK B pins to the smart cards can be programmed for various modes. Both synchronous and asynchronous cards are supported. There are several options available with asynchronous cards. Table 3 shows how all clock options are obtained using bits D5–D7 (card B) and D13–D15 (card A). The default state of the LTC1955 on power up is synchronous mode.

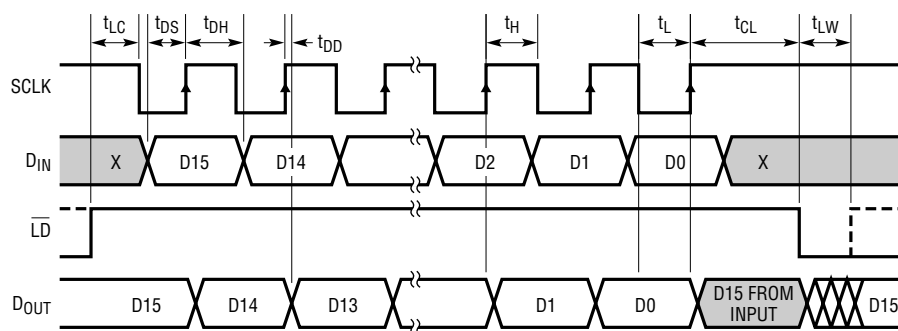


Figure 2. Serial Port Timing Diagram

OPERATION

Table 1. Serial Port Commands

	STATUS OUTPUT	BIT	COMMAND INPUT
CARD B	0	D0	V _{CCB} Options
	0	D1	(See Table 2)
	0	D2	Card B Select/Deselect
	0	D3	Data Pull-Up Defeat
	Card B Electrical Fault	D4	Reserved (Always Set to "0")
	Card B ATR Fault	D5	Card B Clock Options
	Card B V _{CC} Ready	D6	(See Table 3)
	Card B Present	D7	
CARD A	0	D8	V _{CCA} Options
	0	D9	(See Table 2)
	0	D10	Card A Select/Deselect
	0	D11	Card A Communications
	Card A Electrical Fault	D12	Options (See Table 4)
	Card A ATR Fault	D13	Card A Clock Options
	Card A V _{CC} Ready	D14	(See Table 3)
	Card A Present	D15	

Table 2. V_{CC} and Shutdown Options

D9 D1	D8 D0	Status (Card A) Status (Card B)
0	0	V _{CC} = 0V (Shutdown)
0	1	V _{CC} = 1.8V
1	0	V _{CC} = 3V
1	1	V _{CC} = 5V

Table 3. Clock Options

D7 D15	D6 D14	D5 D13	Clock Mode Card B Clock Mode Card A
0	0	0	Synchronous Mode
0	0	1	Unused
0	1	0	Asynchronous Stop Low
0	1	1	Asynchronous Stop High
1	0	0	Asynchronous +1
1	0	1	Asynchronous +2
1	1	0	Asynchronous +4
1	1	1	Asynchronous +8

To receive status data from the serial port, a read/write operation must be performed. When polling for the presence of a smart card on both channels, the input word should be set to \$0000 since this is the shutdown command for the LTC1955. However, consider the example where some operation is already being performed on channel A. If, for example, the previous command was \$BE00 (V_{CCA} set to 3V, card selected, I/O A connected to DATA and CLK A set to ASYNC+2), then the commands for this channel must be rewritten to the serial port each time. To poll for the presence of a card on channel B, or even the V_{CCA} READY status, then \$BE00 should be rewritten on each new read/write cycle. Once a card is detected on channel B, the commands for channel B can be changed but the \$BExx should continue to be rewritten for channel A.

Bidirectional Channels

The bidirectional channels are level shifted to the appropriate V_{CCA/B} voltages at the I/O A/I/O B pins.

An NMOS pass transistor performs the level shifting. The gate of the NMOS transistor is biased such that the transistor is completely off when both sides have relinquished the channel. If one side of the channel asserts an L, then the transistor will convey the L to the other side. Note that current passes from the receiving side of the channel to the transmitting side. The low output voltage of the receiving side will be dependent upon the voltage at the transmitting side plus the I • R drop of the pass transistor.

When a card socket is selected, it becomes a candidate to drive data on the DATA pin and likewise receive data from the DATA pin. When a card socket is deselected, the voltage on its I/O A/I/O B pin will return to the idle state (H) and the DATA side of that channel will become high impedance. If both cards are deselected, the DATA pin will be high impedance.

Both cards may be deselected at the same time to allow communication with a second LTC1955.

Card channel A includes provision for unidirectional communication with the C4 and C8 pins of the smart card. The C4, C8 and I/O pins of card A are individually multiplexed to the DATA pin using bits D11 and D12 as shown in Table 4.

OPERATION

Table 4. Card A Communications Options

D12	D11	Card A Communication Mode
0	0	Nothing Selected
0	1	C4A Connected to DATA Pin
1	0	C8A Connected to DATA Pin
1	1	I/O A Connected to DATA Pin

Note that if a reset is initiated with both cards selected, then both may give an answer to reset and collide on the DATA line. No damage will occur but data could be lost or corrupted.

Dynamic Pull-Up Current Sources

The current sources on the bidirectional pins (DATA, I/O A/ I/O B) are dynamically activated to achieve a fast rise time with a relatively small static current*. Once a bidirectional pin is relinquished, a small start up current begins to charge the node. An edge rate detector determines if the pin is released by comparing its slew rate with an internal reference value. If a valid transition is detected, a large pull-up current enhances the edge rate on the node. The higher slew rate corroborates the decision to charge the node thereby affecting a dynamic form of hysteresis.

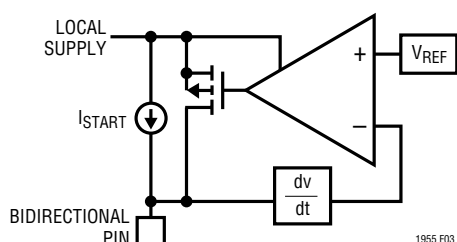


Figure 3. Dynamic Pull-Up Current Sources

Clock Channels

As described in the section Serial Port, the LTC1955 supports both synchronous and asynchronous smart cards. On start-up, or when bits D13-D15 for card A and bits D5-D7 for card B are set to 0s, the clock channel is in synchronous mode. The remaining modes are used for asynchronous cards.

In synchronous mode the CLK A/CLK B pins follow the SYNC pin for a channel that is selected. If a channel is deselected (via the serial port) the CLKA/CLKB line for that channel is latched at its current value.

In asynchronous mode the CLK A/CLK B pins follow either the ASYNC pin ($\div 1$ mode) or a divided version of this pin. The CLK A/CLK B pins can also be stopped high or low. The available divider ratios include $\div 2$, $\div 4$ and $\div 8$. When switching between divider ratios, the internal selection circuitry ensures that no spikes or glitches appear on the CLK A/CLK B pins. Consequently, it may take up to 8 clock pulses for the clock frequency change command to take effect. Synchronization circuitry ensures that no glitches occur when entering or exiting one of the stop modes. For example, when entering stop low mode, the selection circuitry waits for the next falling edge of the respective CLK A/CLK B signal to make the change. Likewise if stop high is selected it will occur on the next rising edge.

Deselection of an asynchronous card does not affect its CLK A/CLK B pin. Its clock can be started, stopped or its divider ratio changed at any time.

To clean up the duty cycle of the incoming clock in asynchronous applications, any of the clock divider modes $\div 2$, $\div 4$ or $\div 8$ will yield a very nearly 50% duty cycle.

Additional synchronization circuitry prevents glitches from occurring when switching between synchronous mode and asynchronous mode. Because of this circuitry, two edges (a falling edge followed by a rising edge) are necessary at the CLK pin to switch modes from asynchronous to synchronous. For example, if clock stop mode is engaged, the clock channel will not change modes until clock stop mode is disengaged.

Any combination of cards, synchronous or asynchronous, can be used as both channels can be set to any of the clock modes or divider ratios independently.

Both SYNC and ASYNC inputs are independently level shifted to the appropriate voltage for the CLK A/CLK B pins (5V, 3V, 1.8V).

Reset Channels

When a card is selected, the reset channels provide a level shifted path from the R_{IN} pin to the RST A/RST B pins. When a card is deselected its RST A/RST B pin is latched at the current value of R_{IN} .

*U.S. Patent No. 6,356,140

OPERATION

Smart Card Detection Circuits

The PRES A/PRES B pins are used to detect the presence of a smart card. An automatic debounce circuit waits until a smart card has been present for a continuous period of typically 35ms. Once a valid card indication exists, the status bit for that channel is updated and may be polled by cycling data through the serial port. The D_{OUT} pin (equivalent to D15) of the serial port can be used to indicate the presence of a card on channel A in real time if $\overline{\text{LD}}$ is held low.

The PRES A/PRES B pins have built-in pull-up current sources so no external components are required for switch detection. The pull-up current sources are designed to have a small current when the pin voltage is below approximately 1V but somewhat higher current when the pin voltage reaches 1V. This helps maintain low power dissipation when a card is present and yet fast response time to a card removal.

The PRES A/PRES B pins can be configured to respond to either normally open or normally closed switches via the NC/ $\overline{\text{NO}}$ pin.

Activation/Deactivation

For maximum flexibility, the activation sequencing of the smart card is left to the application programmer. Upon activation, to comply with relevant smart card standards, none of the smart card signal pins will be allowed to go high before the smart card supply voltage ($V_{\text{CCA}}/V_{\text{CCB}}$) has reached its final value. Deactivation can be achieved either manually or automatically. An electrical fault condition will trigger the automatic deactivation.

Manual deactivation may be performed under software control by setting the smart card pins to 0V in the desired sequence via the control pins (SYNC, ASYNC, R_{IN}, DATA and the serial port). For most applications this will be cumbersome and the built-in deactivation will be used instead.

Automatic Deactivation

The built-in deactivation sequence can be executed via the serial port simply by setting the appropriate control bits (D0 and D1 or D8 and D9) to 0. The deactivation sequence is outlined below.

1. The RST A/RST B pin for that channel is immediately brought low.
2. The deactivation of the CLK A/CLK B pins depends upon which type of card is used:

If the smart card was set to asynchronous mode then the CLK A/CLK B pin will be latched low on its next falling edge. If no falling edges occur within 5 μ s (min) then the CLK A/CLK B line is forced low.

If the smart card was set to synchronous mode then the CLK A/CLK B pin is immediately latched at its current value (either high or low) and then forced low after a duration of 5 μ s (min). During the 5 μ s timeout period changes on SYNC will be ignored.

3. The I/O A/I/O B, C4A and C8A pins for that channel are brought low.
4. The $V_{\text{CCA}}/V_{\text{CCB}}$ pin is brought low.

If an error occurs on one smart card, operation of the other card is unaffected.

OPERATION

Electrical Fault Detection

Several types of faults are detected by the LTC1955. They include V_{CCA}/V_{CCB} undervoltage, V_{CCA}/V_{CCB} overcurrent, CLK A/CLK B, RST A/RST B, C8A, C4A short circuit, card removal during a transaction, failed answer to reset (ATR), supply undervoltage or $\overline{\text{UNDERV}}$ and chip overtemperature. To prevent false errors from plaguing the microcontroller, the electrical faults are acted upon only after a 5 μ s (min) timeout period. Card removal during transaction faults initiate the deactivation sequence immediately.

V_{CCA}/V_{CCB} under voltage faults are determined by comparing the actual output voltage with the internal reference voltage. If the output is more than ~5% below its set point for the entire timeout period, the fault is reported and the deactivation sequence is initiated.

V_{CCA}/V_{CCB} overcurrent faults are detected by comparing the output current of the LDOs with an internal reference level. If the current of an LDO is more than 100mA (typ) for the entire timeout period, the fault is reported and the deactivation sequence is initiated.

CLK A/CLK B and RST A/RST B faults are detected by comparing the outputs of these pins with their expected signals. If the signal on a pin is incorrect for the entire timeout period, the fault is reported and the deactivation sequence is initiated.

The clock channels are a special case. Since they can have a free running clock, the error indication is accumulated over a longer period of time without being cleared. Even though the clock may be running, an error will still be detected.

An overtemperature fault is detected by sensing the junction temperature of the IC. If the junction temperature exceeds approximately 150°C for the entire timeout period, the fault is reported by setting both fault bits (D4 and D12) and the deactivation sequence is initiated.

A card removal fault is determined as soon as the PRES A/ PRES B pin is high (for NC/ $\overline{\text{NO}}$ = 0). Once this occurs the fault is reported and the deactivation sequence is initiated.

If no card is present, and the application software attempts to power up a card socket, an automatic fault will result on that channel.

Short circuits on the I/O A/I/O B lines will not be detected by the fault detection hardware; however, a short circuit from these lines to their respective V_{CCA}/V_{CCB} pins will be compliant with the maximum current limits set by applicable standards (<15mA).

An electrical fault can be cleared on either channel by setting the voltage of that channel to 0V. Set D0 and D1 to 00 to clear channel B and set D8 and D9 to 00 to clear channel A. It is not necessary to set all four bits to zeros.

Answer to Reset (ATR) Fault Detection

Answer to Reset faults are detected by an internal counter that is started once the RST A/B line goes high. If the DATA pin remains high for 40,000 clock cycles, the ATR fault bit for a given channel is set in the serial port's status register (see Table 1) and the FAULT pin is brought low.

An ATR fault can not occur if the clock mode of a channel is set to synchronous. ATR faults will only occur for asynchronous smart cards.

ATR faults are cleared by bringing the RST A/B pin low for the faulted channel. This will also clear the FAULT pin to the Hi-Z state (assuming no other errors are causing FAULT to be low).

An ATR fault will not automatically deactivate a card channel. It is the application programmer's responsibility to check the status register for ATR faults and deactivate the smart card channel in accordance with smart card standards. Generally the application has 50ms (EMV 2.1.3.1, 2.1.3.2) from the 40,000th clock pulse to deactivate the card. Once the LTC1955 receives the deactivation command, it will shut down a card channel in less than 250 μ s.

Using the FAULT Pin

The $\overline{\text{FAULT}}$ pin can be used as an interrupt to a microcontroller. It is an open-drain output and generally requires a pull-up resistor. The FAULT pin will go low when either an electrical fault or an answer to reset fault occurs on either channel. Thus there are four possible faults that can cause it to indicate a problem. The serial port's status register must be polled to find out what type of fault occurred and on which channel. The FAULT pin is logically equivalent to $\overline{\text{D4+D5+D12+D13}}$ (see Table 1).

APPLICATIONS INFORMATION

10kV ESD Protection

All smart card pins (CLK A/CLK B, RST A/RST B, I/O A/I/O B, C4A, C8A and V_{CCA}/V_{CCB}) can withstand over 10kV of human body model ESD in-situ. In order to ensure proper ESD protection, careful board layout is required. The PGND and SGND pins should be tied directly to a ground plane. The V_{CCA}/V_{CCB} capacitors should be located very close to the V_{CCA}/V_{CCB} pins and tied immediately to the ground plane.

Capacitor Selection

Warning: A polarized capacitor such as tantalum or aluminum should never be used for the flying capacitor since its voltage can reverse upon start up of the LTC1955. Low ESR ceramic capacitors should always be used for the flying capacitor.

A total of six capacitors are required to operate the LTC1955. An input bypass capacitor is required at PV_{BATT} , SV_{BATT} and DV_{CC} . Output bypass capacitors are required on each of the smart card V_{CCA}/V_{CCB} pins. A charge pump flying capacitor is required from C^+ to C^- and a charge storage capacitor is required on the charge pump out pin CPO.

To prevent excessive noise spikes due to charge pump operation, low ESR (equivalent series resistance) multi-layer ceramic capacitors are strongly recommended.

There are several types of ceramic capacitors available each having considerably different characteristics. For example, X7R/X5R ceramic capacitors have excellent voltage and temperature stability but relatively low packing density. Y5V ceramic capacitors have apparently higher packing density but poor performance over their rated voltage or temperature ranges. Under certain voltage and temperature conditions, Y5V and X7R/X5R ceramic capacitors can be compared directly by case size rather than specified value for a desired minimum capacitance.

Placement of the capacitors is critical for correct operation of the LTC1955. Because the charge pump generates large current steps, all of the capacitors should be placed as close to the LTC1955 as possible. The low impedance nature of multilayer ceramic chip capacitors will minimize voltage spikes but only if the power path is kept very short

(i.e., minimum inductance). The PV_{BATT}/SV_{BATT} nodes should be especially well bypassed. The capacitor for this node should be directly adjacent to the QFN package. The C_{PO} and flying capacitors should be very close as well. The LTC1955 can tolerate more distance between the LDO capacitors and the $V_{CCA/B}$ pins.

Figure 4 shows an example of a tight printed circuit board using single layer copper. For best performance a multi-layer board can be used and should employ a solid ground plane on at least one layer.

The following capacitors are recommended for use with the LTC1955:

	Type	Value	Case Size	Murata P/N
C_{IN} CPO	X5R	4.7 μ F	0805	GRM40-034 X5R 475K 6.3
C_{FLY} $V_{CCA/B}$	X5R	1 μ F	0603	GRM39 X5R 105K 6.3
CDV_{CC}	X5R	0.1 μ F	0402	GRM36 X5R 104K 10

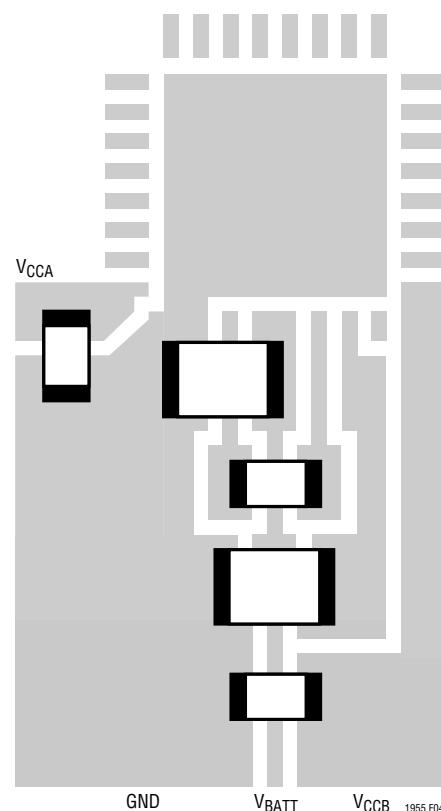


Figure 4. Optimum Single Layer PCB Layout

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APPLICATIONS INFORMATION

Interfacing to a Microcontroller

The serial port of the LTC1955 can be connected directly to a 68HC11 style microcontroller's serial port. The microcontroller should be configured as the master device and its clock's idle state should be set to high (MSTR = 1, CPOL = 1 and CPHA = 0 for the MC68HC11 family). Figure 4 shows the recommended configuration and direction of data flow. Note that an additional I/O line is necessary for $\overline{\text{LD}}$ to load the data once it has shifted around the loop. Command data is latched into the command register on the falling edge of the $\overline{\text{LD}}$ signal. The LTC1955 will begin to act on new command data as soon as $\overline{\text{LD}}$ goes low. Any general purpose microcontroller I/O line can be configured to control the $\overline{\text{LD}}$ pin.

The status of the LTC1955 is returned over the serial port. Status data is latched into the shift register on the rising edge of the $\overline{\text{LD}}$ pin. Whenever the system is waiting for status data from the LTC1955, its $\overline{\text{LD}}$ pin should be held low.

Daisy-Chained Operation

For applications requiring more than two card sockets, the serial port of the LTC1955 is designed to be easily daisy-chained. The D_{OUT} pin of one LTC1955 can be connected directly to the D_{IN} pin of another LTC1955. Rather than sending two 8-bit bytes before asserting $\overline{\text{LD}}$, the microcontroller should send two 8-bit bytes per device. $\overline{\text{LD}}$ should only be asserted after all devices have been updated. Figure 7 shows three LTC1955s cascaded in daisy chain fashion. In this case the microcontroller would write six 8-bit bytes before asserting the $\overline{\text{LD}}$ pin. Alternatively, if two serial ports are available on the microcontroller, then two LTC1955s can be controlled independently.

If the DATA lines of two or more LTC1955s are connected together, the static pull-up current will be the sum of the devices. The static current can be brought back to the level of a single LTC1955 by setting bit D3 on all but one of the LTC1955s to 1 (see Table 1). Bit D3 disables the pull-up current source on the DATA pin. This will help prevent V_{OL} problems in multiple LTC1955 applications when driving the DATA or I/O pins low.

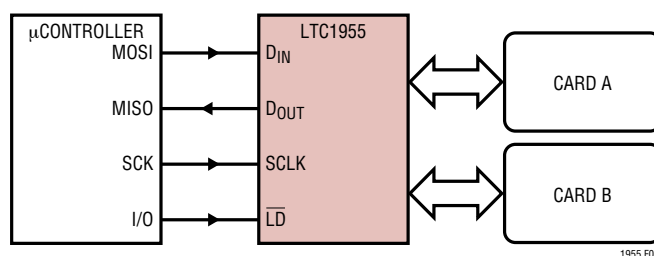


Figure 5. Microcontroller Interface

APPLICATIONS INFORMATION

Using S.A.M. Cards

For applications using one or more installed S.A.M. cards, the PRES A/PRES B pins for those sockets must be grounded before operation of the card can occur (assuming NC/ $\overline{\text{NO}}$ is grounded). The PRES A/PRES B pull-up current is designed for very low consumption, but ultralow current can be achieved in shutdown by using a microcontroller output to pull down on the PRES A/PRES B pins only when communication is necessary. The fault detection circuitry will not allow a card socket to be operated unless a card is detected.

Asynchronous Channel A Card Detection

Since the shift register is transparent when $\overline{\text{LD}}$ is held low, D_{OUT} is the same as D15. Recall from Table 1 that D15 indicates the status of the card detection channel for channel A. Thus, it is not necessary to perform an entire read/write operation to determine the card detection status of channel A. With $\overline{\text{LD}}$ low, D_{OUT} can be used to generate a real time card detection interrupt. This could be useful for one S.A.M. card, one smart card application.

Inter Card Communication

Communication is possible directly from one card socket to the other when both cards are selected at the same time. This can be achieved by the following sequence of actions.

- 1) Start with both cards off and deselected
- 2) Activate the supply of the slave card
- 3) Select the slave card only
- 4) Initiate a reset on the slave card
- 5) Deselect the slave card
- 6) Activate the supply of the master card
- 7) Select the master card only
- 8) Initiate a reset on the master card
- 9) Select both cards

Using the $\overline{\text{UNDERV}}$ Pin

The $\overline{\text{UNDERV}}$ pin can be used to add protection against a supply undervoltage fault. By using two external programming resistors, the undervoltage detection can be set to an arbitrary level (Figure 8). To ensure that the smart cards are properly shut down, there must be sufficient energy available in the input bypass capacitor to run one or both smart cards until the deactivation cycle begins. It can take approximately $30\mu\text{s}$ from the detection of a fault until the deactivation sequence begins. It is desirable to maintain the V_{BATT} supply at 2.7V or greater during this period.

Consider the following (worst-case) example:

- 1) The $\overline{\text{UNDERV}}$ pin is programmed to trip below 3.1V.
- 2) It is possible to have both cards activated at 5V and drawing 60mA.

Since the output voltage is programmed to 5V, the charge pump will be acting as a voltage doubler. With two cards drawing 60mA each, the input current will be $2 \cdot (60\text{mA} + 60\text{mA})$ or about 240mA. Allowing the V_{BATT} supply to droop from 3.1V to 2.7V during the $30\mu\text{s}$ timeout period, the input capacitance would need to be at least $240\text{mA} / [(3.1\text{V} - 2.7\text{V}) / 30\mu\text{s}]$ or $18\mu\text{F}$.

Thermal Management

To minimize power dissipation, the LTC1955 will actively decide whether to step up or down depending on the required output voltages and available input voltage. However, for optimum efficiency, the LTC1955 should be powered from a 3.3V supply.

If the input voltage is above 3.6V, and both cards are drawing maximum current, there can be substantial power dissipation in the LTC1955. If the junction temperature increases above approximately 150°C , the thermal shutdown circuitry will automatically deactivate both channels. To reduce the maximum junction temperature, a good thermal connection to the PC board is recommended.

Zero Shutdown Current

Although the LTC1955 is designed to have very low shutdown current, it can still draw over a microampere on

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both DV_{CC} and V_{BATT} when in shutdown. For applications that require virtually zero shutdown current, the DV_{CC} pin can be grounded. This will reduce the V_{BATT} current to well under a single microampere. Internal logic ensures that the LTC1955 is in shutdown when DV_{CC} is grounded. Note, however, that all of the logic signals that are referenced to DV_{CC} (D_{IN} , $SCLK$, $\overline{LD}$, $DATA$, R_{IN} , $SYNC$, $ASYN$ C and NC/NO) will have to be at 0V as well to prevent ESD diodes to DV_{CC} from being forward biased.

Operation at Higher Supplies

If a 5.5V to 6V supply voltage is available, it is possible to achieve some power savings by bypassing the charge pump. The higher supply can be connected directly to the CPO pin. As long as the voltage on CPO is higher than that at which it ordinarily regulates (5.35V or 3.7V depending on voltage selections) the charge pump's oscillator will not run. This configuration can give considerable power savings since the charge pump is not being used.

A voltage source is still needed on both DV_{CC} and SV_{BATT}/PV_{BATT} in this configuration. Recall that DV_{CC} sets the logic reference level for all the control and smart card communication pins. The voltage on SV_{BATT}/PV_{BATT} can be any convenient level that meets the parameters in the Electrical Characteristics table.

The 5.5V to 6V supply can be left permanently connected to CPO but there will be approximately 5 μ A of current flow into CPO when the LTC1955 is in shutdown.

Charge Pump Strength

Under low V_{BATT} conditions, the amount of current available to the smart cards is limited by the charge pump.

Figure 6 shows how the LTC1955 can be modeled as a Thevenin equivalent circuit to determine the amount of current available given the effective input voltage, $2V_{BATT}$ and the effective open-loop output resistance, R_{OLCP} .

From Figure 6, the available current is given by:

$$I_{CCA} + I_{CCB} \leq \frac{2V_{BATT} - V_{CPO}}{R_{OLCP}}$$

R_{OLCP} is dependent on a number of factors including the switching term, $1/(f_{OSC} \cdot C_{FLY})$, internal switch resistances and the nonoverlap period of the switching circuit. However, for a given R_{OLCP} , the minimum CPO voltage can be determined from the following expression:

$$V_{CPO} \geq 2V_{BATT} - (I_{CCA} + I_{CCB})R_{OLCP}$$

The LDOs have been designed to meet all applicable smart card standards for V_{CC} with V_{CPO} as low as 5.13V. Given this information, trade-offs can be made by the user with regard to total consumption ($I_{CCA} + I_{CCB}$) and minimum supply voltage.

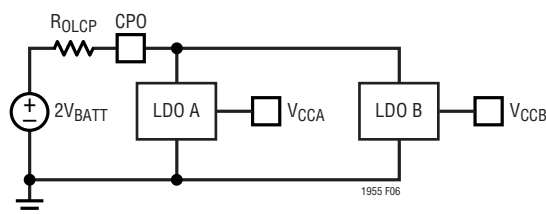


Figure 6. Equivalent Open-Loop Circuit

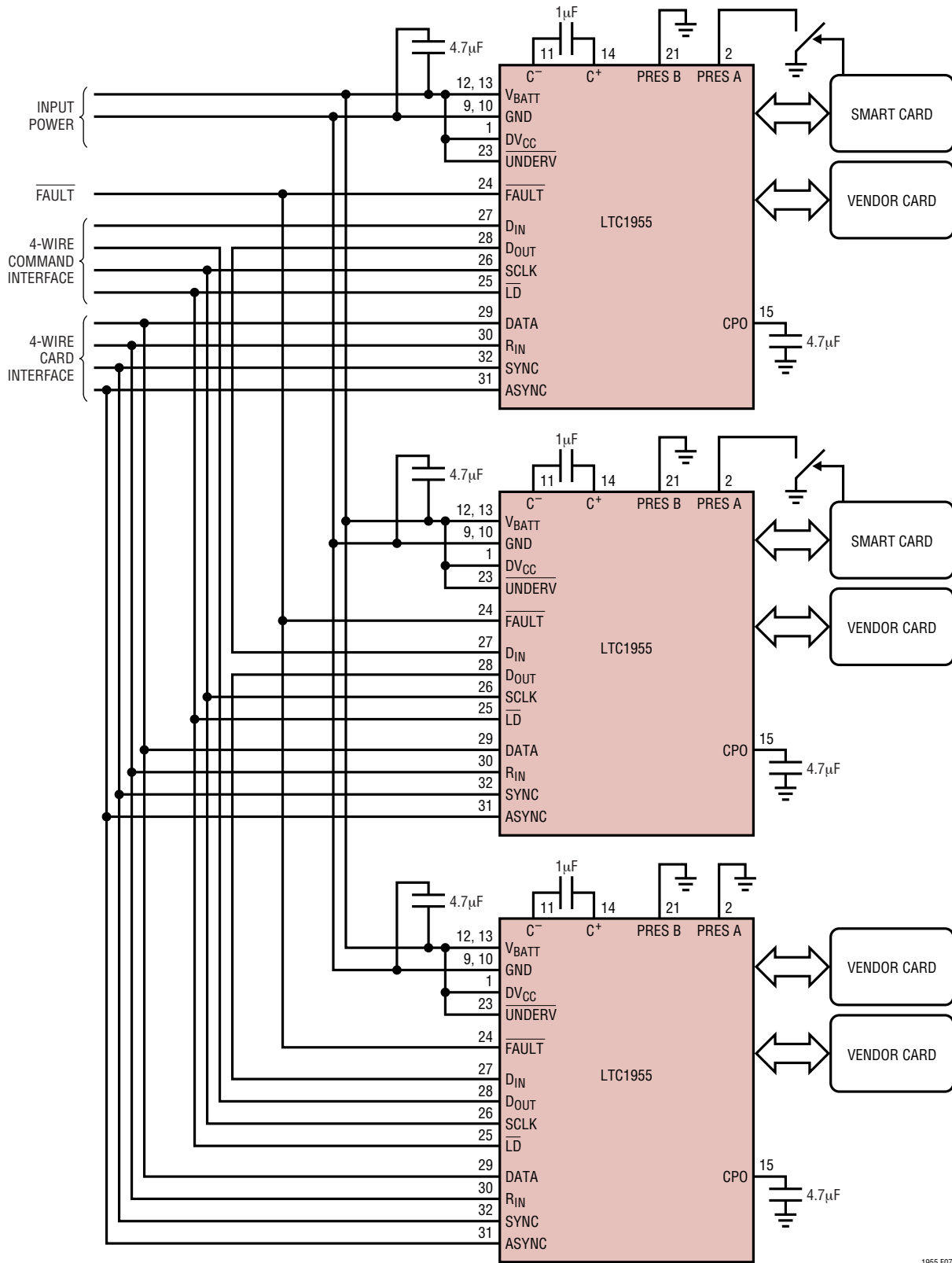
Changing the Smart Card Supply Voltage

Although the LTC1955 control system will allow the smart card voltage to be changed from one value to the next without an interim power down, this is not recommended. When changing from a higher voltage to a lower voltage there will generally not be a problem; however, changing from a lower voltage to a higher voltage will result in both an undervoltage condition and an overcurrent condition on that channel. The likely result is that the channel will automatically deactivate. Applicable smart card standards specify that the smart card supply be powered to zero before applying a new voltage.

Compliance Testing

Inductance due to long leads on type approval equipment can cause ringing and overshoot that leads to testing problems. Small amounts of capacitance and damping resistors can be included in the application without compromising the normal electrical performance of the LTC1955 or smart card system. Generally a 100 Ω resistor and a 20pF capacitor will accomplish this as shown in Figure 9.

APPLICATIONS INFORMATION



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Figure 7. Multiple LTC1955s Daisy Chained Together

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APPLICATIONS INFORMATION

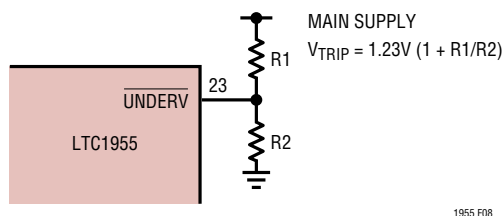


Figure 8. Setting the Undervoltage Trip Point

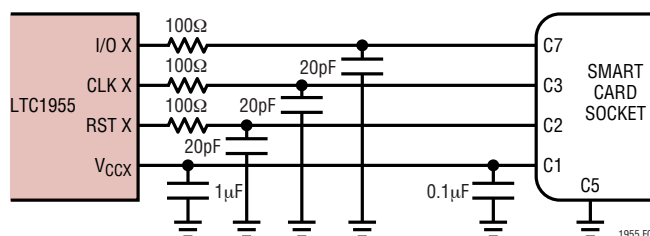
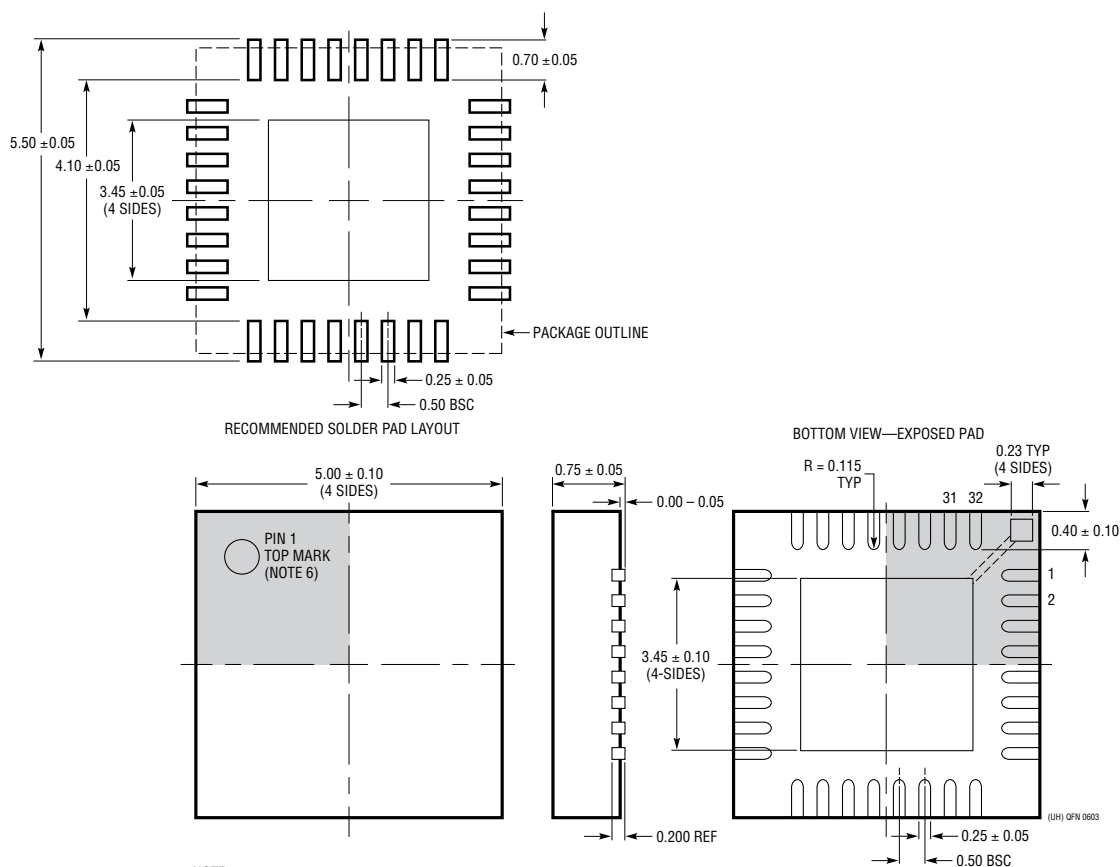


Figure 9. Additional Components for Improved Compliance Testing

PACKAGE DESCRIPTION

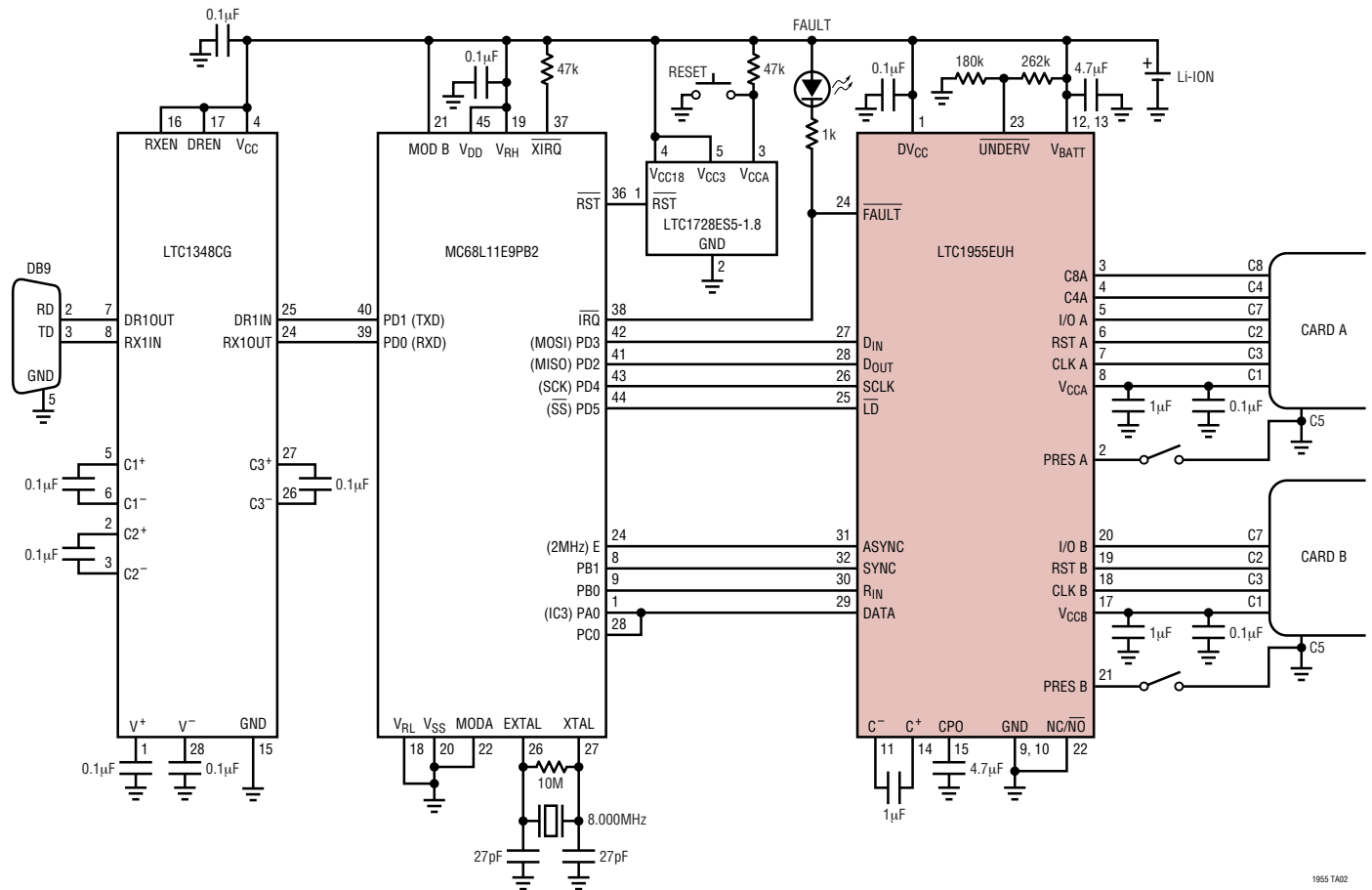
UH Package 32-Lead Plastic QFN (5mm × 5mm) (Reference LTC DWG # 05-08-1693)



- NOTE:
1. DRAWING PROPOSED TO BE A JEDEC PACKAGE OUTLINE MO-220 VARIATION WHHD-(X) (TO BE APPROVED)
 2. DRAWING NOT TO SCALE
 3. ALL DIMENSIONS ARE IN MILLIMETERS
 4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.20mm ON ANY SIDE
 5. EXPOSED PAD SHALL BE SOLDER PLATED
 6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

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TYPICAL APPLICATION



Battery Powered RS232 to Dual Smart Card Interface

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RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC1755/LTC1756	ISO 7816-3 and EMV Compatible Smart Card Interface	$V_{OUT} = 3V/5V$, $V_{IN} = 2.7V$ to $6V$, SSOP-16/-24 Package
LTC1555	SIM Power Supply and Level Translator Step-Up/Step-Down Charge Pump	$V_{OUT} = 3V/5V$, $V_{IN} = 2.7V$ to $10V$, SSOP-16/-20 Package
LTC1555L-1.8	SIM Power Supply and Level Translator Step-Up/Step-Down Charge Pump	$V_{OUT} = 1.8V/3V/5V$, $V_{IN} = 2.6V$ to $6V$, SSOP-16 Package
LTC4555	SIM Power Supply and Level Translator	$V_{OUT} = 1.8V/3V$, $V_{IN} = 3V$ to $6V$, $3mm \times 3mm$ QFN Package
LTC4556	SIM Power Supply and Level Translator	$V_{OUT} = 1.8V/3V$, $V_{IN} = 3V$ to $6V$, $3mm \times 3mm$ QFN Package
LTC4557	SIM Power Supply and Level Translator	$V_{OUT} = 1.8V/3V$, $V_{IN} = 3V$ to $6V$, $3mm \times 3mm$ QFN Package

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